Dead time duration and active reset influence on the afterpulse probability of InGaAs/InP SPAD based SPDs

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Abstract

We perform the detailed study of the afterpulse probability’s dependence in the InGaAs/InP sine-gated SPAD on the dead time and the used approach for its implementation. We have found that the comparator’s simple latching can significantly reduce afterpulses’ probability, even without using a dead time pulse that lowers the diode bias voltage. We have found that with a low probability of afterpulse (< 5 %) or with a large dead time (τ > 10 μs), it is sufficient to use a circuit with latching of the comparator, which will significantly simplify the development of an SPD device for applications in which such parameters are acceptable. We also proposed a precise method for measuring and the afterpulse and presented a model describing the recurrent nature of this effect. We have shown that it should not use a simple model to describe the afterpulse probability due to rough underlying physical processes. A second-order model is preferable.
1 Introduction

Detectors based on superconducting nanowires (SNSPD) [1] and the single photon avalanche diodes (SPAD) [2] have proven themselves in the best way as single-photon detectors (SPDs). Each of the implementations has both its advantages and disadvantages. SNSPD has a high probability of photon detection and low noise level, but it is large and quite expensive. SPAD-based SPDs have a small size and low cost, but the detection probability is relatively low, and the noise characteristics are high. In QKD, both the first and the second type of SPD have found their application [3, 4]. It is advisable to use SNSPD for key distribution over long distances, both over fiber and open space. It is on SNSPD based QKD was demonstrate the key distribution distance records [5]. It is advisable to use SPAD-based SPD in small-sized industrial installations [6] that distribute the key within one city or even one building since the loss of photons in the line is minimal and the key generation rate is high enough.

One of the big problems of the QKD is the difficulty of determining the generated key’s secrecy. In contrast to classical cryptographic algorithms, in which the applied mathematical transformations strictly determine the key’s confidentiality, quantum cryptography depends on the installation’s physical parameters [7]. Thus, the calculated key secrecy can be selected too pessimistically, which will significantly reduce the key generation rate or optimistically endanger the security of subsequently encrypted data. For this reason, the development of methods for accurate determination of the parameters of SPD is an actual task that can significantly increase the efficiency of the QKD installation as a whole [8].

In the SNSPD with good enough control electronics, there are no effects associated with previous triggers [9]. That is, we can consider all processes as Markovian [10]. There is a ”memory” of earlier triggers in SPAD-based SPDs – the processes has more complicate influence on counting statistics [11], and the construction of a global SPD model becomes complicated. Charges captured by the traps cause this memory. These charges relax after a particular time, which can be determined experimentally, and is called afterpulses [12].

For detectors for 1550 nm wavelength photons, based on InGaAs/InP SPAD, the total relaxation time is about $10 - 50 \, \mu s$ at a temperature of about $-100 - -50 \, ^\circ C$. For Si-based photon detectors for visible radiation, the full relaxation time is about 200 ns [13]. As methods of struggle of this effect, we can use SPD circuits with dead time - the time during which a new triggering cannot be recorded on the detector after the previous triggering. However, suppose the complete relaxation of the traps is expected. In that case, the InGaAs/InP SPAD used in SPD in QKD receives significant restrictions on the limiting operating frequencies, which harms the installation’s efficiency as a whole. Therefore, to obtain the SPD’s highest efficiency for the QKD application, the dead time value is reduced to $1 - 10 \, \mu s$ while sacrificing QBER but gaining the maximum count rate, which is especially important for short distances QKD [14].

The purpose of this work was to develop an accurate method for calculation the detec-
tor’s afterpulse probability from counting statistics. Several models of its calculation were proposed and then analyzed based on experimental data obtained from custom sinusoidal gated SPDs based on InGaAs/InP SPAD. However, the results obtained are also applicable to SPD based on other SPAD structures.

It was proposed the different approaches to extract the afterpulse probability from the counting statistics [15–18]. But there is no consensus on which experimental setup, it’s settings and models should be using for obtaining afterpulse probability. In our work we compare the afterpulse probability, obtained with widely used simple model [15] and our own model. We got a result, that afterpulse probability value sufficiently differs with applied model.

We also analyzed the requirement for the addition of an active reset module after triggering. This research gives recommendations on setting the time parameters of latching the detector sensitivity based on statistical data analysis and the processes’ physics. Also, the empirical models’ parameters approximating the experimental data, which allows them to be used in subsequent global SPD models, were given.

2 Simple and complex afterpulse models

The afterpulse probability - the probability that the next detector’s trigger (“click”) generated by the afterpulse mechanism will occur after any trigger [8]. According to this definition, the afterpulse click can trigger the next afterpulse click (second-order afterpulses). This effect is negligible for low afterpulse probabilities ($p_{ap} < 5\%$) but should be carefully accounted for high. In this section, we will present two different models – ”Simple” and ”Complex”. The advantage of the simple model is its simplicity and possibility of easy $p_{ap}$ calculating from the statistics. The advantage of the complex model is that it is an accurate statistical description of afterpulse processes in the diode.

The simple model’s main idea is the afterpulse click probability $P_{ap}^s$ can be derived from photon-, thermal-, tunneling- induced click probabilities $P_0$ by the parameter $p_{ap}^s$.

$$P_{ap}^s = P_0 p_{ap}^s.$$  (1)

In this view, the $P_{ap}^s$ included the second, third, etc. order afterpulses, and its assessment is included in the parameter $p_{ap}^s$. This approach is right for the low afterpulse probabilities because the high-order afterpulses are unlikely. The main drawback is that with varying the $P_0$ by, for example, an increase in the number of photons per pulse, the $p_{ap}^s$ assessment will differ too [14]. We can find the total probability of click $P$ from the schematic diagram 1 a).

The total click probability $P$ can be derived as:

Simple: $P = P_0 + P_{ap}^s - P_0 P_{ap}^s = P_0(1 + p_{ap}^s - P_0 p_{ap}^s)$  (2)
Figure 1: Schematic diagram of afterpulse probability models: a) simple model; b) complex model. $P_0$ is a probability of clicking in a system without afterpulse, $p_{ap}$ – is the afterpulse probability.

In the complex model, we take into account the recursive behavior of the afterpulse. In this case, we can show the next schematic diagram, presented in figure 1. b).

The probability that the clicks $P_0$ will generate an afterpulse is equal to $P_0p_{ap}$. The probability that afterpulses $P_0p_{ap}$ generates the new afterpulses is $P_0p_{ap}$, and so on. The calculation of the overall afterpulse influence on the total probability of click can be performed by a series of consecutive convolutions of probabilities ($P_1, P_2, \text{etc.}$). We can write the next equations:

$$P_1 = P_0 + P_0p_{ap} - P_0P_0p_{ap} = P_0(1 - P_0p_{ap}) + P_0p_{ap},$$

$$P_2 = P_1 + P_0p_{ap}^2 - P_1P_0p_{ap}^2 = P_1(1 - P_0p_{ap}^2) + P_0p_{ap}^2,$$

$$\vdots$$

$$P_{i+1} = \ldots = P_i(1 - P_0p_{ap}^{i+1}) + P_0p_{ap}^{i+1}. \quad (3)$$

This recurrent equation can be rewritten as the decomposition relate parameter $P_0$. To do this, we consider the probabilities of afterpulse events as $\gamma_i$, where $P(\gamma_i) = P_0p_{ap}^i$, and
these events are joint and independent, which means that \( P(\gamma_i \cap \gamma_j) = P(\gamma_i)P(\gamma_j) = P_0^2 p_{ap}^{i+j} \).

\[
P_1 = P(\gamma_0 \cup \gamma_1) = P(\gamma_0) + P(\gamma_1) - P(\gamma_0 \cap \gamma_1) = P_0(1 + p_{ap}) - P_0^2 p_{ap},
\]
\[
P_2 = P(\gamma_0 \cup \gamma_1 \cup \gamma_2) = P(\gamma_0) + P(\gamma_1 \cup \gamma_2) - P(\gamma_0 \cap (\gamma_1 \cup \gamma_2)) = \]
\[= P(\gamma_0) + P(\gamma_1) + P(\gamma_2) - P(\gamma_1 \cap \gamma_2) - (P(\gamma_0 \cap \gamma_1) + P(\gamma_0 \cap \gamma_2) - P(\gamma_0 \cap \gamma_1 \cap \gamma_2)) = \]
\[= P(\gamma_0) + P(\gamma_1) + P(\gamma_2) - P(\gamma_0 \cap \gamma_1) - P(\gamma_0 \cap \gamma_2) - P(\gamma_0 \cap \gamma_1 \cap \gamma_2) + P(\gamma_0 \cap \gamma_1 \cap \gamma_2) = \]
\[= P_0(1 + p_{ap} + p_{ap}^2) - P_0^2 (p_{ap} + p_{ap}^2 + p_{ap}^3) + P_0^3 p_{ap}^3, \]
\[
\vdots
\]
\[
P_n = P(\gamma_0 \cup \gamma_1 \cup \gamma_2 \cup \ldots) = P_0 \sum_{i=0}^{n} p_{ap}^i - P_0^2 \sum_{i,j=0,j>i}^{n} p_{ap}^{i+j} + P_0^3 \sum_{i,j,k=0,k>j>i}^{n} p_{ap}^{i+j+k} + \ldots
\]

(4)

In this recursive equation, \( P_\infty \) is the actual probability of click, which includes the all orders of afterpulses. For ease of use in analytical models, we can take the first and second terms in the appropriate order of \( P_0 \). After that, we will analyze the bounds of applicability of these two decomposition models.

We can calculate the sum of the series of first and second order \( P_0 \) as follows:

\[
\lim_{n \to \infty} \sum_{i=0}^{n} p_{ap}^i = \frac{1}{1 - p_{ap}},
\]
\[
\lim_{n \to \infty} \sum_{i,j=0,j>i}^{n} p_{ap}^{i+j} = \frac{p_{ap}}{(1 - p_{ap})^2(1 + p_{ap})},
\]

(5)

So, we can derive the first and second-order afterpulse accounting models as:

\[
1\text{st order} : P = P_0 \frac{1}{1 - p_{ap}},
\]
\[
2\text{nd order} : P = P_0 \frac{1}{1 - p_{ap}} - P_0^2 \frac{p_{ap}}{(1 - p_{ap})^2(1 + p_{ap})}.
\]

(6)

In figure 2, we compare the detection probability \( P \), calculating according to simple, first, second, and high order models. We assume that the high-order model (the decomposition of \( P \) with 20th order of \( P_0 \)) is the benchmark, and we should compare the other models with it. We can see that for low afterpulse probability \( p_{ap} = 0.1 \) the all models gives a good convergence with the high order model, and the low deviations begin with increasing the \( P_0 \). The first model gives the largest error. However, for the higher values of \( p_{ap} \), we can see that simple and first-order have large deviations. Only a second-order model should be used for accurate estimation of total click probability \( P \).
Comparison of afterpulse models ($p_{ap} = 0.1$)

Comparison of afterpulse models ($p_{ap} = 0.3$)

Figure 2: Comparison of the simple, 1st, 2nd and high order models for determining the click probability $P$, assuming that a) $p_{ap} = 0.1$, b) $p_{ap} = 0.3$.

3 Afterpulse measurement approach

The afterpulse measurements can only be done by processing the triggers histogram, presented in figure 3. In the experimental setup, we set the laser pulse repetition rate equal to 10 kHz and with energy $\approx 1$ ph/pulse, i.e., photon arrival time differs on 100 µs. We set the oscilloscope sweep at 25 µs. The photons most likely cause trigger clicks, and these clicks consist of dark counts and afterpulse counts. After the trigger click bin, we have the empty bins during the dead time. In the detector with well established latched time of the comparator, there is no twilight pulses effect, and during the second dead time, the afterpulse can be described by one of the well-researched laws: exponential [19,20], power-law [21], and hyperbolic sinc model [22, 23]. Nevertheless, in practice, this is a non-trivial task to get rid of twilight pulses, and the first bin after dead time presents this effect - it will be lower than the next bin. In the third and other dead time windows, previous afterpulse clicks’ influence distorts the representation of afterpulse law.

As we can see from figure 3 b), the twilight pulse effect is pronounced for low dead time $\tau = 0.21$ µs, then for high dead time $\tau = 7.3$ µs. The measurement time for these two histograms is equal, and we can see that for high time $t > 10$ µs, the count per bin is roughly the same. This figure shows the distribution law of afterpulse and approximates it with one of the three mentioned models.

At the end of the oscilloscope sweep (the range $t_{dcr} \approx [20, 25]$ µs), the count of afterpulse clicks will be negligible, and we can consider that it is mainly due to the dark counts. There is a low probability that photon clicks in this time window because of the last’s low repetition rate. We will argue that all counts that differ from the dark counts have an afterpulse nature for the rough evaluation. Furthermore, the total afterpulse counts can
be found as:

\[ C_{dcr} = \sum_{i \in t_{dcr}} C_i, \]
\[ C_{ap} = \sum_{i \in [0,25] \mu s} (C_i - C_{dcr}), \]  

where \( C_{dcr} \) – is the average DCR counts per bin, \( C_i \) – is the count in \( i \)-th histogram bin, \( C_{ap} \) – is the total counts, that we consider as afterpulse counts.

The \( C_{ap} \) counts include the different orders of afterpulses. We estimate the afterpulse probability as:

\[ p_{ap}^{exp} = \frac{C_{ap}}{C_0 - C_{dcr}}, \]  

where the \( C_0 \) – is the counts in trigger zero bin of histogram.

The sense of the estimated value can be described by picture 1 a): \( p_{ap}^{exp} P_0 \approx P_{ap} - P_{ap} P_0 \).

Moreover, we can derive the \( P_{ap} \) value that should be universal for all models \( P_{ap} = p_{ap}^{exp} P_0 = P_{ap} \) as:

\[ P_{ap} \approx \frac{p_{ap}^{exp} P_0}{1 - P_0} \]  

We can easily calculate the \( p_{ap} \) for simple, single, and second-order afterpulse models.
with this assumption. We can relate the \( p_{ap}^{exp} \) and \( p_{ap}^s \) and \( p_{ap} \) parameters:

\[
P_{ap} = \frac{P_n - P_0}{1 - P_0},
\]

\[
p_{ap}^{exp} P_0 = P_n - P_0,
\]

\[
P_n = P_0(1 + p_{ap}^{exp}),
\]

where we obtained the right-hand side for the first equation from the simple equation for \( P_n \) (\( P \) notation for simple model) probability: \( P_n = P_0 + P_{ap} - P_0 P_{ap} \). The \( P \) and \( P_n \) can be derived from equations 2 and 6 for simple, first and second-order models.

For the simple and first order models, we can get the simple relation for \( p_{ap}^s \) and \( p_{ap}^{(1)} \):

\[
p_{ap}^s = \frac{p_{ap}^{exp}}{1 - P_0},
\]

\[
p_{ap}^{(1)} = 1 - \frac{1}{1 + p_{ap}^{exp}}.
\]

Similarly, we can find the \( p_{ap}^{(2)} \) for the second-order model, but this is a non-trivial task to do it analytically. For this reason, \( p_{ap}^{(2)} \) finds only numerically.

We can find the \( p_{ap}^{(1)} \) value from experimental \( p_{ap}^{exp} \), but to calculate the \( p_{ap}^s \) and \( p_{ap}^{(2)} \), we need to find the \( P_0 \) probability previously. To do this, we need to know the overall probability of click \( P_n \) (or \( P \) for simple model), which we can find from count rate \( R \) and dead time (statistical) \( \tau \): \( P_n = R\tau \) [paper about QE]. After that, we need to paste it into equation 2 or 6 (depends on the observed model) and calculate the \( P_0 \). For the simple model, we can derive the \( p_{ap}^s \) value from \( R \) analytically:

\[
p_{ap}^s = \frac{p_{ap}^{exp}(1 + p_{ap}^{exp})}{1 + p_{ap}^{exp} - R\tau}.
\]

It is evident that with low \( R\tau \) the equation 12 takes the following form: \( p_{ap}^s = p_{ap}^{exp} \).

For the accurate SPD models, one should use the second-order model because \( p_{ap}^{(2)} \) does not depend on the \( P_0 \), and one value of \( p_{ap}^{(2)} \) can be used for a wide range of optical power per pulse \( \mu \) (ph/pulse). The simple model is suitable only for the low values of \( p_{ap}^s \), and when SPD operation is proposed only with fixed \( \mu \). The first-order model suits in the case of low \( p_{ap}^{(1)} \) because, like for the 2nd order model, it can be used for wide (but lower than for 2nd model) range \( \mu \), and simple form of equations allows you to use it in analytical models of SPD.
4 Influence of the active reset on the counting statistics

In this section, we will describe the two different schematic realizations of the dead time, that named "Latched time" (LT) and "Latched time + active reset" (LT + AR) [17, 24]. Latched time $\tau_l$ – the time during that the comparator is locked, and all triggers that occurred before are not detected. Active reset means the additional reduction of the SPAD bias voltage during the schematic dead $\tau_c$ to exclude the trigger probability entirely. The LT scheme’s main advantage is simplicity because adding active reset to the circuit is a non-trivial task. The main disadvantage of the LT scheme is the high afterpulse probability. Many additional triggers (which are not detected) contribute to the accumulation of charge in the traps in the SPAD heterostructure and, therefore, increase the afterpulse probability. In the LT + AR scheme, during the $\tau_c$ occurs relaxation of traps, accordingly lowering the afterpulse probability.

Also, we can define the statistics dead time $\tau_s$ as the time range between some trigger and the next first possible trigger. This time interval depends on $\tau_l$, $\tau_c$, and active reset pulse form. This pulse should be the square in the ideal case, but the leading and trailing edges are distorted due to electronics influence.

Trail edge causes the high amplitude oscillations, which are difficult to learn due to their high-frequency components, making detector performance difficult to predict. To exclude the possible counting of these triggers, we need to make a latched time $\tau_l$ more than schematic dead time $\tau_c$ on the value, approximately equal to the time of these transients $\tau_{er}$. This recovery time can be in the range $200 < \tau_{er} < 3 \, \mu s$, which depends on the circuit realization, but the low values are preferable.

There are different configuration, depends on these time intervals:

- $\tau_l > \tau_c + \tau_{er}$: we present this case in figure 4 a). This figure presents the active reset time and counting statistics for LT and LT + AR schemes (as for the b) picture. Here, latched time fully determines the statistics dead time $\tau_s$: $\tau_s = \tau_l$. Here, $\tau_c \approx 3.65 \, \mu s$ and $\tau_{er} \approx 0.8 \, \mu s$. The difference $\tau_l - \tau_c - \tau_{er} \approx 0.9 \, \mu s$. It means that approximately $0.9 \, \mu s$ in the DT + AR scheme did not detect triggers can occur.

- $\tau_l < \tau_c + \tau_{er}$: we present this case in figure 4 b). Here, $\tau_c \approx 7.5 \, \mu s$, $\tau_{er} \approx 2.5 \, \mu s$, $\tau_l \approx 7.8 \, \mu s$. We can see that the first triggers in the LT + AR scheme occur at $9 \, \mu s$, which is lower than $\tau_c + \tau_{er} = 10 \, \mu s$. The statistics are due to the SPD’s low detection probability when active reset pulse applied to SPAD and its value < 0
because it lowers the bias voltage. The deviation of the initial section of statistics from the mentioned afterpulse laws is determined by the PDE dependence on the SPAD bias voltage. Clicks that occur before the full recovery of the bias voltage on the diode is called twilight pulses.

Figure 4: Active reset influence on the counting statistics: a) $\tau_s = 5.35\,\mu s$; b) $\tau_s = 9.04\,\mu s$. Two statistics were normalized by zero bin click count $C_0 - C_{dcr}$.

The case, in which using the LT + AR scheme and satisfied $\tau_l \approx \tau_c + \tau_{er}$, where $\tau_{er} \approx 400$ ns is preferable. There are no triggers before the latched time to increase the trap’s charge and, consequently, the afterpulse probability. However, setting such a value is a rather non-trivial schematic and technical task.

The next section will compare the LT and LT + AR schemes by the afterpulse probability $p_{ap}$ and show results obtained by simple, first, and second-order models.

5 Results

We tested three custom sinusoidal gated SPDs based on InGaAs/InP SPADs named SPD1, SPD2, and SPD3. These SPADs (with gated frequency $\nu = 312.5$ MHz) were manufactured by Wooriro company and were taken from different batches. The SPAD №2 and №3 have butterfly housing and a built-in enclosure cooling system. We have shown Its main parameters in table ??.
Table 1: Parameters of used SPADs.

<table>
<thead>
<tr>
<th>SPD №</th>
<th>SPAD</th>
<th>T, K</th>
<th>DCR, Hz ($\tau \approx 20 \mu s$)</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td></td>
<td></td>
<td>$R = 1200$ Hz</td>
</tr>
<tr>
<td>1</td>
<td>PA19H262-0004</td>
<td>223</td>
<td>$\approx 250$</td>
</tr>
<tr>
<td>2</td>
<td>MF20C300-0001</td>
<td>233</td>
<td>$\approx 50$</td>
</tr>
<tr>
<td>3</td>
<td>MF20D300-0001</td>
<td>233</td>
<td>$\approx 150$</td>
</tr>
</tbody>
</table>

We add the possibility of enabling or disabling active reset to the circuit realization of SPD. Also, we add the manual setting of the circuit dead time $\tau_c$ and latching time $\tau_l$. In all presented below pictures, it was $\tau_l > \tau_c$. However, due to transients at the trailing edge during the $\tau_{er}$, we cannot accurately set the parameters to achieve the preferable condition: $\tau_l > \tau_c + \tau_{er}$. For this reason, some data was obtained for the first case and another for the second case of time interval configurations, presented above. It means that statistical dead time $\tau_s$ for LT and LT + AR schemes can differ for the similar setting of latched time.

In our experiments, laser pulses with FWHM $\approx 50$ ps and repetition rate 10 kHz were attenuated to the average power per pulse $\mu \approx 1$ ph/pulse. We established two count rates in our experiments: $R \approx 1200$ Hz and $R \approx 2200$ Hz. It means that for low $p_{ap}$ values ($p_{ap} < 5 \%$) $PDE \approx 10 \%$ and $PDE \approx 20 \%$ correspondingly. Nevertheless, for the high $p_{ap}$ values, $PDE$ was lowered. The setting of the $R$ value was performed by changing the SPD’s bias voltage with unchanged gate amplitude. The statistics were collected on an oscilloscope and processed to obtain $p_{ap}^{exp}$ value. After that, we find the $p_{ap}^{(1)}$, $p_{ap}^{(2)}$, which corresponds to simple, first, and second-order models.

In figure 5 a), we present the $p_{ap}$ value for LT and LT + AR schemes obtained for simple and second-order models (diamond and point markers correspondingly). We approximate data for SPD1 and SPD2 curves defined by the power-law equation. Data for SPD3 was approximated with an exponential equation:

\[
\begin{align*}
\text{power law: } p_{ap}^{pl}(\tau) &= A \tau^B + C, \\
\text{exponential: } p_{ap}^{e}(\tau) &= Ae^{-B\tau} + C,
\end{align*}
\]

where the $A$, $B$ and $C$ parameters presented in the table 2 from appendix A.

The common used law for approximate the $p_{ap}$ dependence on the dead time for fixed $PDE$ is the exponential, as shown at works [15–18,25–27]. But in our works we fixed the total counts $R$, that can be considered as fixed $PDE$ only for low $p_{ap}$ (the SPD3 has low $p_{ap}$ and data had been approximated with exponential law quite well). We didn’t fixed the $PDE$ value instead because there is not consensus for it’s definition equation. On contrary, experimentally obtained counting rates can be defined only one way.

Figure 5: SPD1 data: a) Comparing $p_{ap}$ for LT and LT + AR schemes, obtained in accordance to simple and second-order models (diamonds and points correspondingly). Dashed lines represent the fitted curves for simple model, solid lines – for the second-order model; b) Active reset pulse, applied to SPAD after the trigger.

On this figure, we can see that afterpulse probability estimation $p_{ap}$ at the high values and low $\tau$ values sufficiently differs for simple and second-order models – solid and dashed curves. However, for low $p_{ap}$ and high $\tau$ they almost coincide. We can see that using active reset has significant effects on the pap, which is especially noticeable for $R = 2200$ Hz. We can also see that with higher bias voltage on SPAD, which is directly related to $R$, the afterpulse probability is high.

Figure 5 b) presents the active reset pulses. The leading edge is sharp in order to remove possible triggers that may occur quickly. In this case, high-amplitude transient processes occur, but they do not influence triggers. The trailing edge is smoother to reduce the internal transients’ time interval and make its amplitude lower.

Figure 6 is similar to figure 5 but performed for SPD2. We can see that for $R = 2200$ Hz, $p_{ap}$ is sufficiently higher than $p_{ap}$ for SPD1, and vice versa for $R = 1200$ Hz. This feature is not due to the control circuit but due to differences in the SPAD’s characteristics. On the b) picture, we can see that the trailing edge is sufficiently smoother. For SPD1, that can cause intense twilight pulses and reduce SPAD efficiency for high-frequency laser pulse repetition rates.

Figure 7 a) presents the same, as in figures 5 and 6, but for SPD3 data. The afterpulse probability for this detector is small enough even for low dead time and disabled active reset. For the $R = 1200$ Hz data, the LT red curve lies lower than LT + AR green curve. Here it is already a matter of measurement errors and the features of the approximation of experimental data.

Figure 7 b) compares the $p_{ap}^{(1)}$, $p_{ap}^{(2)}$ with $p_{exp}^{ap}$ for the SPD2 data and $R = 2200$ Hz. We can see that the first and second-order models have a satisfactory agreement for high afterpulse probabilities and sufficiently differ from experimentally obtained $p_{exp}^{ap}$. 

12
These models differ for the afterpulse probability $p_{ap}^{exp} < 15 \%$. The simple model for a high $p_{ap}^{exp} > 15 \%$ tends to this $p_{ap}^{exp}$ value. However, for a lower $p_{ap}^{exp}$, it has even more value. There is no sufficient difference between the LT or LT + AR schemes – they converge quite well on these graphs.

We can make the main conclusions of this schedule:

- There is no difference in $p_{ap}$ for the LT and LT + AR schemes for high $\tau$ values and low $R$ (related with PDE) rates. If SPD is not designed with strict requirements for the limiting count rates and quantum efficiency, then it is permissible not to use a circuit with active reset pulses.

- Choosing a model for calculating the $p_{ap}$ is essential for high afterpulse probabilities ($p_{ap}^{exp} > 5 \%$) – first, or second-order models are preferable. For low values $p_{ap}^{exp}$, we can use a simple model too. According to the simple model, we get a strongly overestimated value of the afterpulse, which coincides with the experimentally found one.

6 Conclusion

The main result of the work is that we compare schemes with latching time (LT) and with latching time and active reset (LT + AR) and it’s influence on the afterpulse probability. As a result of the experiments, we have shown that the active reset module could significantly reduce afterpulse probability. However, with a large dead time ($\tau > 10 \mu s$) and generally low afterpulse probabilities ($p_{ap}^{exp} < 5 \%$), the differences between the
Figure 7: a) SPD3 data: comparing of $p_{ap}$ for LT and LT + AR schemes, obtained in accordance to simple and second-order models (diamonds and points correspondingly). Dashed lines represent the fitted curves for simple model, solid lines – for the second-order model; b) SPD2 data: comparing of $p_{ap}^{s}$, $p_{ap}^{(1)}$ and $p_{ap}^{(2)}$ with $p_{ap}^{exp}$ for the SPD2 data and $R = 2200$ Hz.

two schemes are relatively insignificant. With low requirements for the detector ($\tau > 5 \ \mu s$ and $PDE = 10 \%$), the possibility of abandoning the active reset module will significantly simplify the detector’s circuit design. At the same time, not significantly increase the afterpulse probability.

The second result is the developed approach to determining the probability of afterpulses of detectors, following three models. We have described the procedure for processing statistics from the oscilloscope histograms to obtain the experimental afterpulse probability. We introduce three models: simple, 1-st and 2-nd order. We obtain, that simple model is bad enough for description the afterpulsing counting statistics due to rough underlied physical processes. As a result of the experiments, it was shown that the use of the simple model gives rough results, which at high afterpulse probabilities tend to the simple experimentally obtained values. We have shown that it is best to use a second-order model, which should give correct results for both small and large afterpulse probabilities. If the use of the analytical applications model is required, then the first-order model should be used because of its simple algebraic form. The obtained with this model results have small deviations from the second-order model with the afterpulse probability $p_{ap}^{exp} < 15 \%$, but for large values, they coincide well.

Other work results are the given recommendations for setting the values of the circuit dead time and latching time from the conditions of the internal transient time. Also, tables with fitted parameters were presented, approximating the results obtained for a simple model and a second-order model, which allows using these dependencies in the global SPD model.
## Table with fitted parameters

For the simple and second order models we present the parameters of fitted curves in the table 2:

Table 2: Parameters of the fitted curves for simple and second order models.

<table>
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<tr>
<th>SPD №</th>
<th>Fit equation</th>
<th>Scheme</th>
<th>$R$, Hz</th>
<th>Model</th>
<th>A</th>
<th>B</th>
<th>C</th>
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References


